



FMMT614

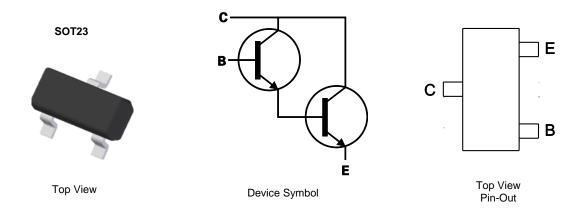
#### 100V NPN DARLINGTON MEDIUM POWER TRANSISTOR IN SOT23

#### **Features**

- BV<sub>CEO</sub> > 100V
- I<sub>C</sub> = 0.5A High Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- 500mW Power Dissipation
- Darlington Transistor with High h<sub>FE</sub> up to 5k at I<sub>C</sub> = 0.5A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (FMMT614Q)

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 🔞
- Weight: 0.008 grams (Approximate)



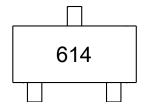
#### **Ordering Information** (Note 4)

| Part Number | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT614TA   | AEC-Q101   | 614     | 7                  | 8               | 3,000             |
| FMMT614TC   | AEC-Q101   | 614     | 13                 | 8               | 10.000            |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



614 = Product Type Marking Code



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | 120   | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | 100   | V    |
| Emitter-Base Voltage         | V <sub>EBO</sub> | 10    | V    |
| Continuous Collector Current | Ic               | 500   | mA   |
| Peak Pulse Current           | I <sub>CM</sub>  | 2     | A    |

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic                                   | Symbol                            | Value       | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5)                       | P <sub>D</sub>                    | 500         | mW   |
| Thermal Resistance, Junction to Ambient (Note 5) | R <sub>θJA</sub>                  | 250         | °C/W |
| Thermal Resistance, Junction to Lead (Note 6)    | $R_{	heta JL}$                    | 197         | °C/W |
| Operating and Storage Temperature Range          | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

# ESD Ratings (Note 7)

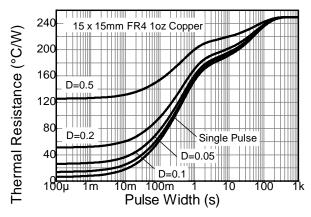
| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge – Human Body Model | ESD HBM | 2,000 | V    | 2           |
| Electrostatic Discharge – Machine Model    | ESD MM  | 200   | V    | В           |

Notes:

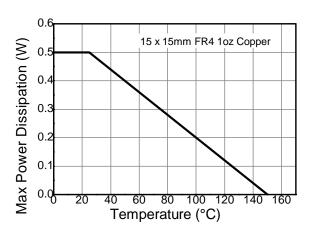
<sup>5.</sup> For a device mounted on 15mm x 15mm 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Thermal resistance from junction to solder-point (at the end of the collector lead).
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



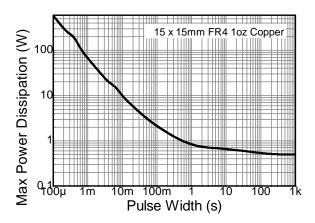
# **Thermal Characteristics and Derating Information**



**Transient Thermal Impedance** 



**Derating Curve** 



**Pulse Power Dissipation** 



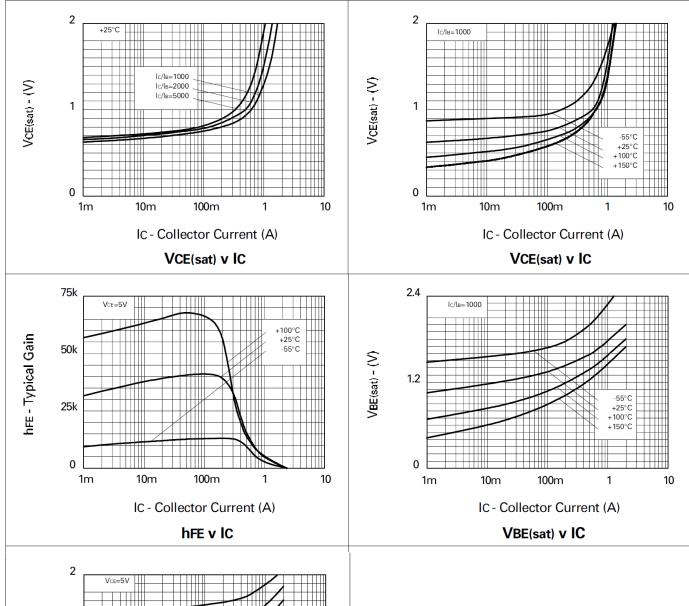
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                 | Symbol               | Min       | Тур         | Max        | Unit   | Test Condition   |
|--|----------------------|-----------|-------------|------------|--------|--|
| Collector-Base Breakdown Voltage               | BV <sub>CBO</sub>    | 120       | 300         | _          | V      | $I_C = 10\mu A$  |
| Collector-Emitter Breakdown Voltage (Note 8)   | BV <sub>CEO</sub>    | 100       | 130         | _          | V      | I <sub>C</sub> = 10mA  |
| Emitter-Base Breakdown Voltage                 | BV <sub>EBO</sub>    | 10        | 14          | _          | V      | $I_E = 10\mu A$  |
| Collector Cutoff Current                       | I <sub>CBO</sub>     | _         | 0.02        | 10         | nA     | V <sub>CB</sub> = 100V   |
| Emitter Cutoff Current                         | I <sub>EBO</sub>     | _         | _           | 100        | nA     | V <sub>EB</sub> = 8V   |
| Collector Emitter Cutoff Current               | I <sub>CES</sub>     | _         | _           | 10         | μΑ     | V <sub>CE</sub> = 100V   |
| Static Forward Current Transfer Ratio (Note 8) | h <sub>FE</sub>      | 15k<br>5k | _           | _          | _      | I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V<br>I <sub>C</sub> = 500mA, V <sub>CE</sub> = 5V |
| Collector-Emitter Saturation Voltage (Note 8)  | V <sub>CE(SAT)</sub> | _         | 0.9<br>0.78 | 1.0<br>0.9 | V<br>V | $I_C = 500 \text{mA}, I_B = 5 \text{mA}$<br>$I_C = 100 \text{mA}, I_B = 0.1 \text{mA}$       |
| Base-Emitter Turn-On Voltage (Note 8)          | V <sub>BE(ON)</sub>  | _         | 1.5         | 1.8        | V      | I <sub>C</sub> = 500mA, V <sub>CE</sub> = 5V   |
| Base-Emitter Saturation Voltage (Note 8)       | V <sub>BE(SAT)</sub> | _         | 1.7         | 1.9        | V      | $I_C = 500 \text{mA}, I_B = 5 \text{mA}$   |
| Output Capacitance                             | C <sub>OBO</sub>     | _         | 6           | _          | pF     | V <sub>CB</sub> = 10V, f = 100mHz  |
| Switching Times                                | t <sub>ON</sub>      | _         | 0.7         | _          | μs     | $I_C = 100\mu A, I_B = 0.1 mA,$  |
| Switching filles                               | t <sub>OFF</sub>     | _         | 2.5         | _          | μs     | V <sub>S</sub> = 10V   |

Note: 8. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

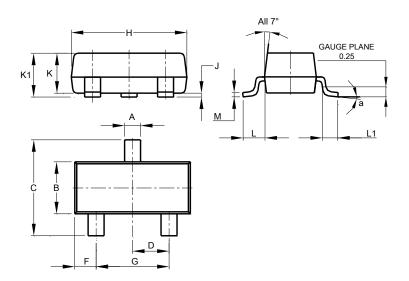




## **Package Outline Dimensions**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

#### SOT23

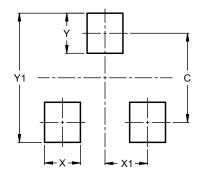


| SOT23                |       |       |       |  |  |
|----------------------|-------|-------|-------|--|--|
| Dim                  | Min   | Max   | Тур   |  |  |
| Α                    | 0.37  | 0.51  | 0.40  |  |  |
| В                    | 1.20  | 1.40  | 1.30  |  |  |
| С                    | 2.30  | 2.50  | 2.40  |  |  |
| D                    | 0.89  | 1.03  | 0.915 |  |  |
| F                    | 0.45  | 0.60  | 0.535 |  |  |
| G                    | 1.78  | 2.05  | 1.83  |  |  |
| Н                    | 2.80  | 3.00  | 2.90  |  |  |
| J                    | 0.013 | 0.10  | 0.05  |  |  |
| K                    | 0.890 | 1.00  | 0.975 |  |  |
| K1                   | 0.903 | 1.10  | 1.025 |  |  |
| L                    | 0.45  | 0.61  | 0.55  |  |  |
| L1                   | 0.25  | 0.55  | 0.40  |  |  |
| M                    | 0.085 | 0.150 | 0.110 |  |  |
| а                    | 0°    | 8°    | _     |  |  |
| All Dimensions in mm |       |       |       |  |  |

## **Suggested Pad Layout**

 $Please see AP02001 \ at \ http://www.diodes.com/\_files/datasheets/ap02001.pdf \ for \ the \ latest \ version.$ 

#### SOT23



| Dimensions | Value (in mm) |  |  |
|------------|---------------|--|--|
| С          | 2.0           |  |  |
| Х          | 0.8           |  |  |
| X1         | 1.35          |  |  |
| Y          | 0.9           |  |  |
| Y1         | 2.9           |  |  |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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